



Package: QFN, 4 mmx4 mm



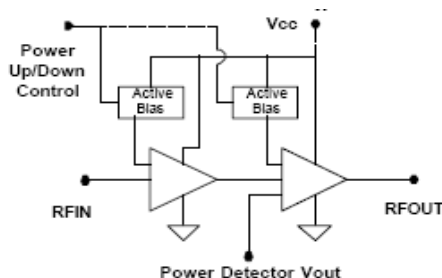
Product Description

RFMD's SZA-2044 is a high efficiency class AB Heterojunction Bipolar Transistor (HBT) amplifier housed in a low-cost surface-mountable plastic package. This HBT amplifier is made with InGaP on GaAs device technology and fabricated with MOCVD for an ideal combination of low cost and high reliability. This product is specifically designed as a final stage 802.11b/g and 802.16 equipment in the 2.0GHz to 2.7GHz bands. It can run from a 3V to 5V supply. Optimized on-chip impedance matching circuitry provides a 50Ω nominal RF input impedance. The external output match and bias adjustability allows load line optimization for other applications over narrower bands. It features an output power detector, on/off power control, and high RF overdrive robustness. This product is available in a ROHS Compliant and Green package with matte tin finish, designated by the "Z" package suffix.

Optimum Technology Matching® Applied

- ☐ GaAs HBT
- ☐ GaAs MESFET
- ☒ InGaP HBT
- ☐ SiGe BiCMOS
- ☐ Si BiCMOS
- ☐ SiGe HBT
- ☐ GaAs pHEMT
- ☐ Si CMOS
- ☐ Si BJT
- ☐ GaN HEMT
- ☐ RF MEMS

Functional Block Diagram



Features

- Z Part Number is Available in RoHS Compliant, Pb-Free, and RFMD Green
- 802.11g 54 Mb/s Class AB Performance
- P_{OUT} = 22 dBm at 3% EVM, 5V, 340 mA
- P_{OUT} = 18 dBm at 3% EVM, 3.3V, 175 mA
- On-Chip Output Power Detector
- P_{1dB} = 29.5 dBm at 5V, P_{1dB} = 25 dBm at 3.3V
- Robust - Survives RF Input Power = +15 dBm
- Power Up/Down Control < 1 μs
- Available in RoHS Green Compliant Package

Applications

- 802.11b/g WLAN, 2.4 GHz ISM Applications

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Frequency of Operation	1900		2700	MHz	
Output Power at 1dB Compression		29.5		dBm	2.4 GHz
	28.0	29.5		dBm	2.5 GHz
Small Signal Gain	23.5	25.5	27.5	dB	2.4 GHz
	23.5	25.5	27.5	dB	2.5 GHz
Output power		22		dBm	2.4 GHz, 3% EVM 802.11g 54 Mb/s
		22		dBm	2.5 GHz
Noise Figure		6.1		dB	2.5 GHz
Third Order Intermod		-44.0	-40.0	dBc	2.5 GHz, 18 dBm per tone, 3% EVM with IEEE802.11g 54 Mbps
Worst Case Input Return Loss	10.0	13.0		dB	2.4 GHz to 2.5 GHz
Worst Case Output Return Loss	9.0	11.0		dB	2.4 GHz to 2.5 GHz
Output Voltage Range		0.9 to 1.7		V	P_{OUT} = 15 dBm to 29 dBm
Quiescent Current	255	300	345	mA	V_{CC} = 5V
Power Up Control Current		1.9		mA	V_{PC} = 5V, (I_{VPC1} + I_{VPC2})
Off V_{CC} Leakage Current		6.0	100.0	uA	V_{PC} = 0V
Thermal Resistance		28		°C/W	junction - lead

Test Conditions: Z_0 = 50Ω, V_{CC} = 5V, I_Q = 300 mA, T_{BP} = 30 °C

Absolute Maximum Ratings

Parameter	Rating	Unit
VC2 Collector Bias Current (I_{VC2})	500	mA
VC1 Collector Bias Current (I_{VC1})	150	mA
Device Voltage (V_D), No RF drive	7.0	V
Power Dissipation	3	W
Operating Lead Temperature (T_J)	-40 to +85	°C
Max RF Input Power for 50Ω output load	15	dBm
Max RF Input power for 10:1 VSWR RF out load	8	dBm
Storage Temperature Range	-40 to +150	°C
Operating Junction Temperature (T_J)	+150	°C
ESD Rating - Human Body Model Class 1C (HBM)	500	V
Moisture Sensitivity Level	MSL-1	

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:

$$I_D V_D < (T_J - T_{JL}) / R_{TH, j-I}$$



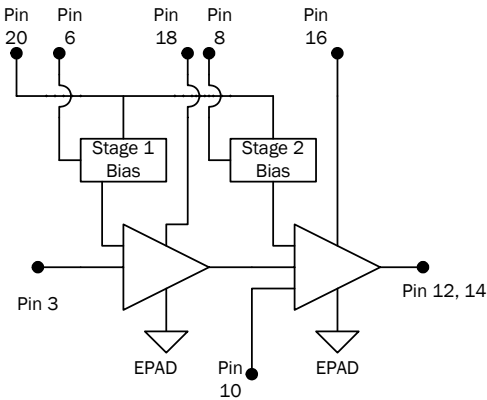
Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

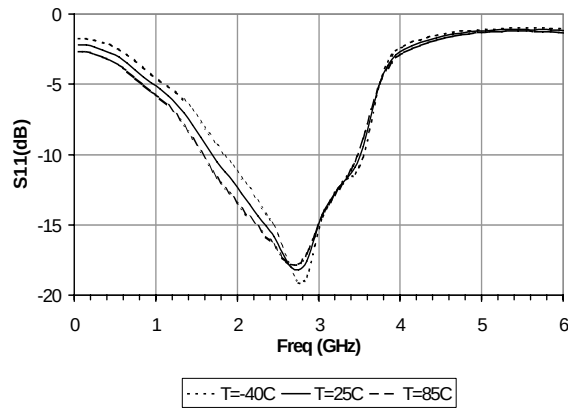
The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

Simplified Device Schematic

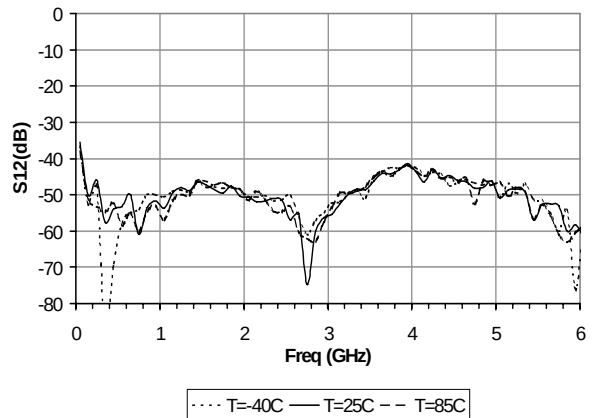


Performance: 2.3GHz to 2.7GHz Evaluation Board Data ($V_{CC}=V_{PC}=5.0V$, $I_Q=300mA$)

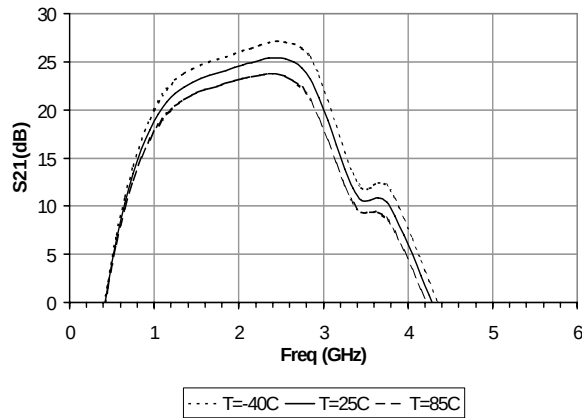
S11 - Input Return Loss



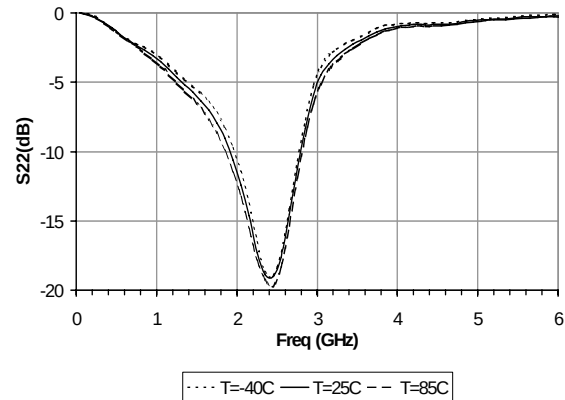
S12 - Isolation



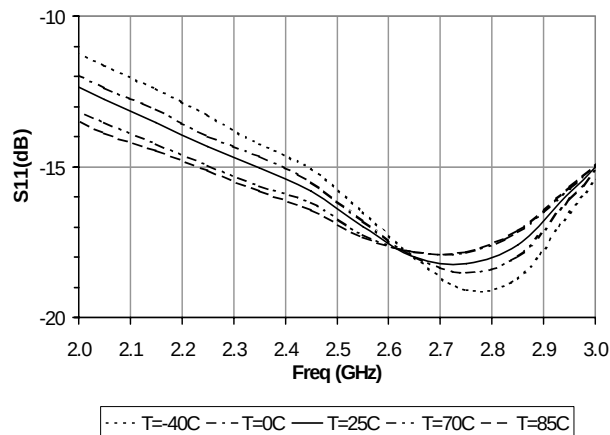
S21 - Gain



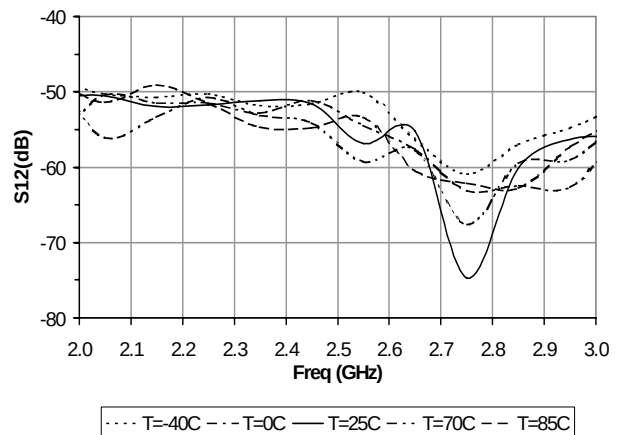
S22 - Output Return Loss



Narrowband S11 - Input Return Loss

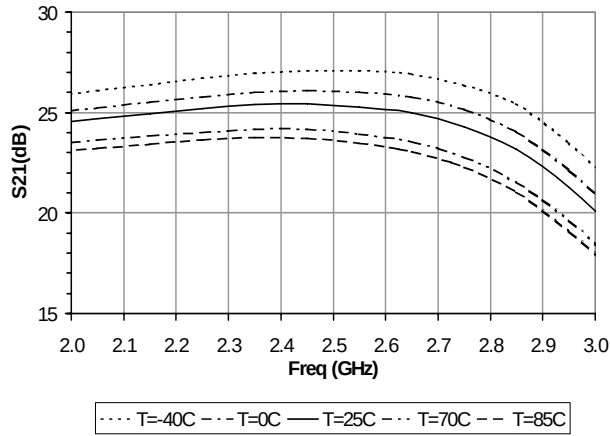


Narrowband S12 - Isolation

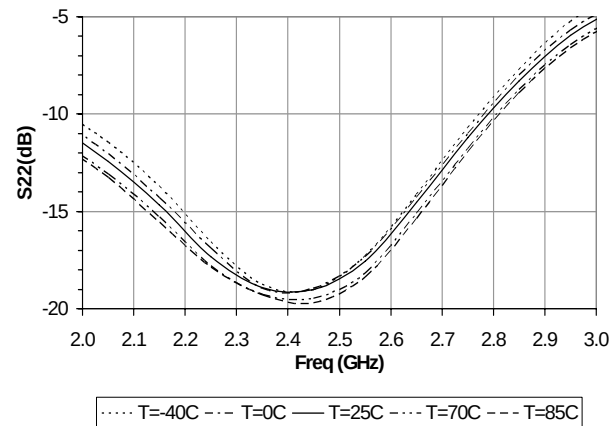


Performance: 2.3GHz to 2.7GHz Evaluation Board Data ($V_{CC}=V_{PC}=5.0V$, $I_Q=300mA$)

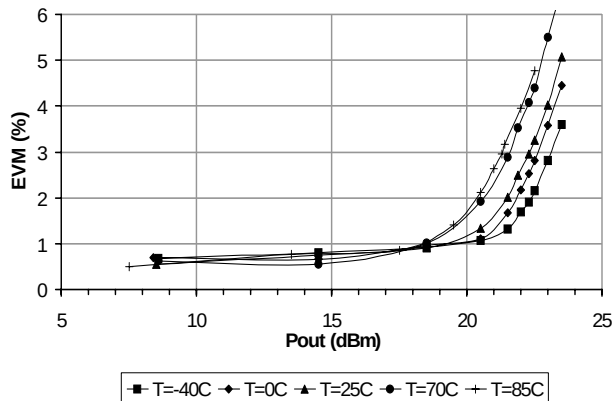
Narrowband S21 - Gain



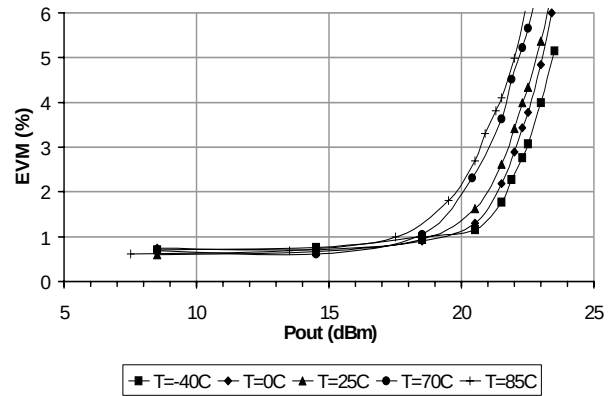
Narrowband S22 - Output Return Loss



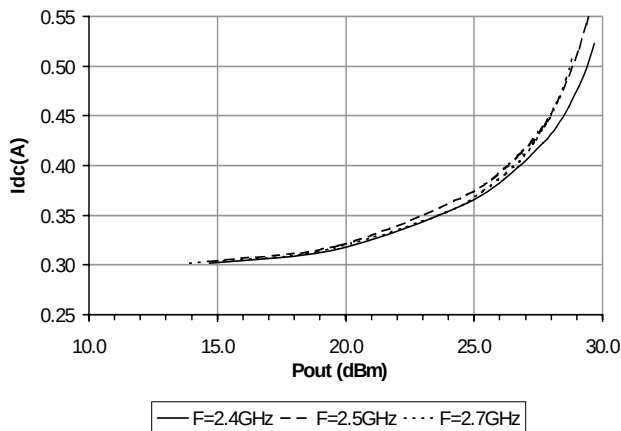
EVM vs Pout, F=2.4GHz
802.11g, OFDM, 54 Mb/s, 64QAM



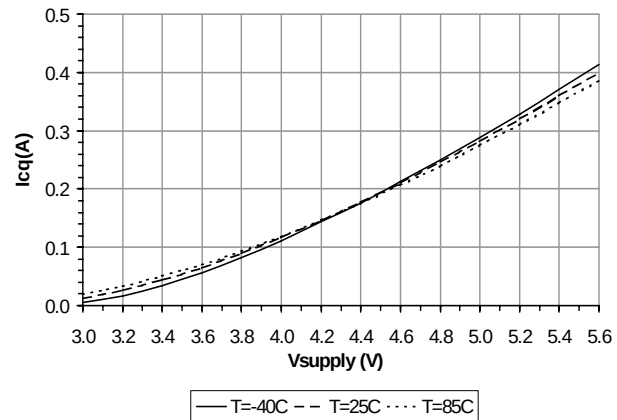
EVM vs Pout, F=2.5GHz
802.11g, OFDM, 54 Mb/s, 64QAM



DC Supply Current (Idc) vs Pout, T=25C

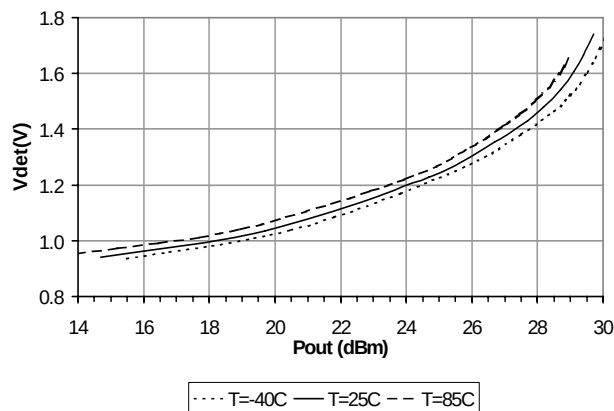


Icq (DC Bias Point) vs Vsupply (V+ and Vpc)

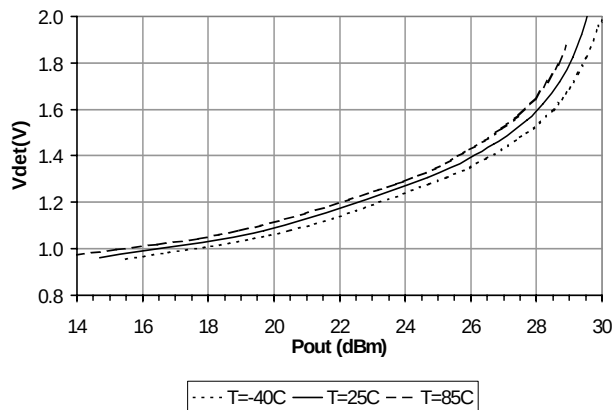


Performance: 2.3GHz to 2.7GHz Evaluation Board Data ($V_{CC}=V_{PC}=5.0V$, $I_Q=300mA$)

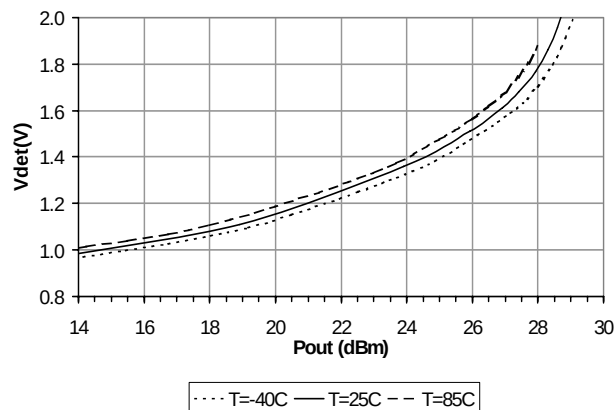
**RF Power Detector (Vdet) vs Pout
F=2.4GHz**



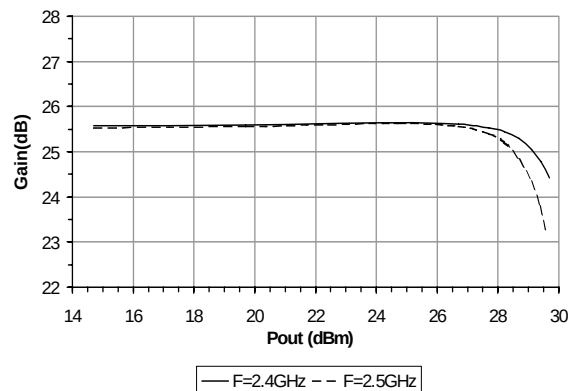
**RF Power Detector (Vdet) vs Pout
F=2.5GHz**



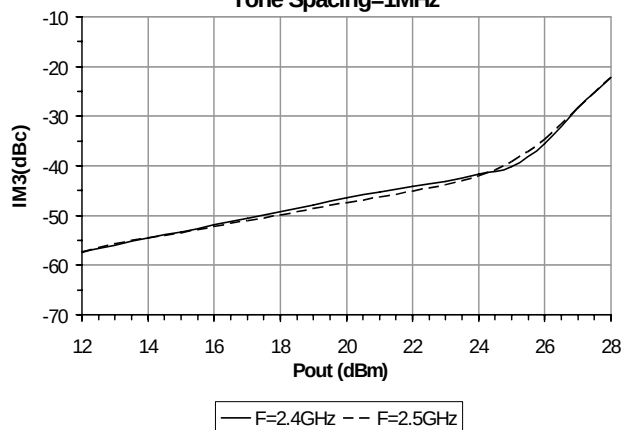
**RF Power Detector (Vdet) vs Pout
F=2.7GHz**



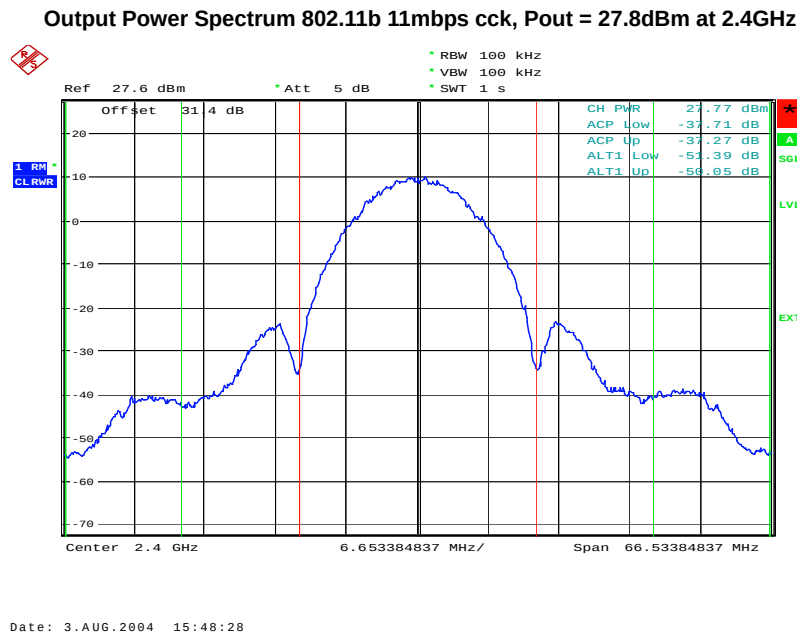
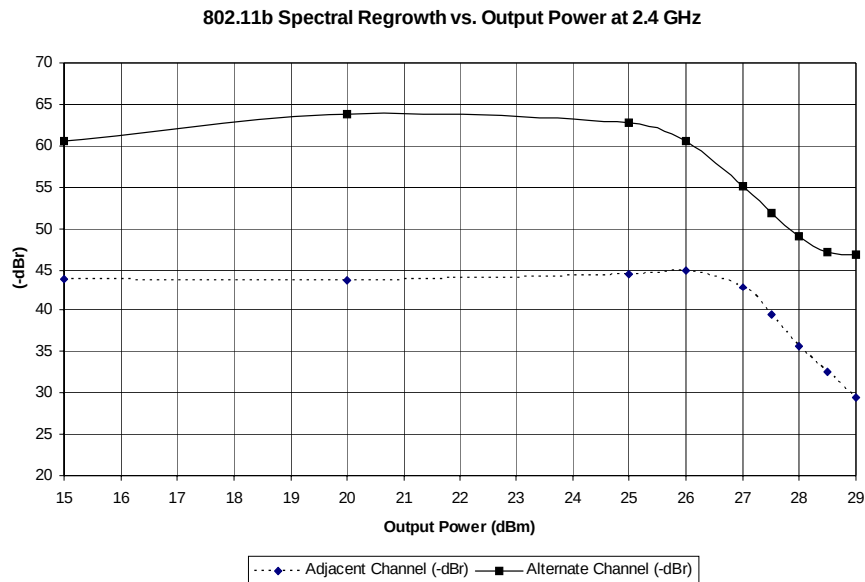
Gain vs Pout, T=25C



**IM3 vs Pout (2 tone avg.), T=25C
Tone Spacing=1MHz**

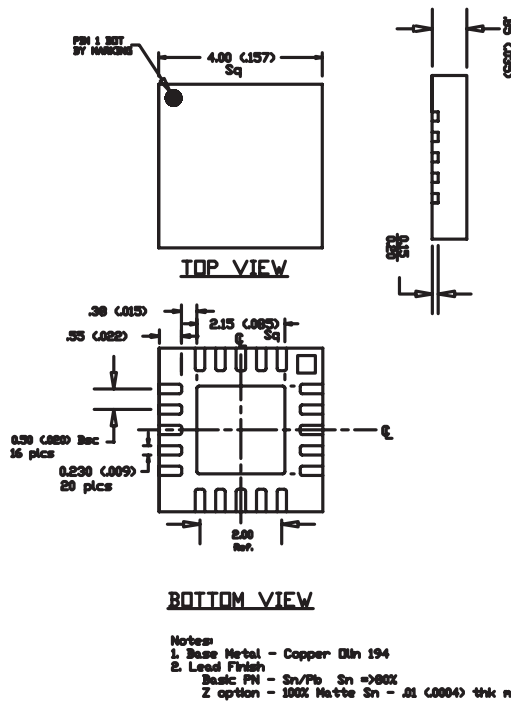


Performance: 2.3GHz to 2.7GHz Evaluation Board Data ($V_{CC}=V_{PC}=5.0V$, $I_Q=300mA$)



Pin	Function	Description
1, 2, 4, 5, 7, 9, 11, 13, 15, 17, 19	N/C	These are unused pins and not wired inside the package. They may be grounded or connected to adjacent pins.
6	VPC1	VPC1 is the bias control pin for the stage 1 active bias circuit. An external series resistor is required for proper setting of bias levels. Refer to the evaluation board schematic for resistor value. To prevent potential damage, do not apply voltage to this pin that is +1V greater than voltage applied to pin 20 (Vbias) unless Vpc supply current capability is less than 10mA.
8	VPC2	VPC2 is the bias control pin for the stage 2 active bias circuit. An external series resistor is required for proper setting of bias levels. Refer to the evaluation board schematic for resistor value. To prevent potential damage, do not apply voltage to this pin that is +1V greater than voltage applied to pin 20 (Vbias) unless Vpc supply current capability is less than 10mA.
10	VDET	Output power detector voltage. Load with >10K Ω for best performance
3	RF IN	RF input pin. This is DC grounded internal to the IC. Do not apply voltage to this pin.
12, 14	RF OUT	RF output pin. This is also another connection to the 2nd stage collector.
16	VC2	2nd stage collector bias pin. Apply 3.0V to 5.0V to this pin.
18	VC1	1st stage collector bias pin. Apply 3.0V to 5.0V to this pin.
20	VBIAS	Active bias network VCC. Apply 3.0V to 5.0V to this pin.
EPAD	GND	Exposed area on the bottom side of the package needs to be soldered to the ground plane of the board for optimum thermal and RF performance. Several vias should be located under the EPAD as shown in the recommended land pattern.

Package Drawing
Dimensions in Millimeters (Inches)
Refer to drawing posted at www.rfmd.com for tolerances.

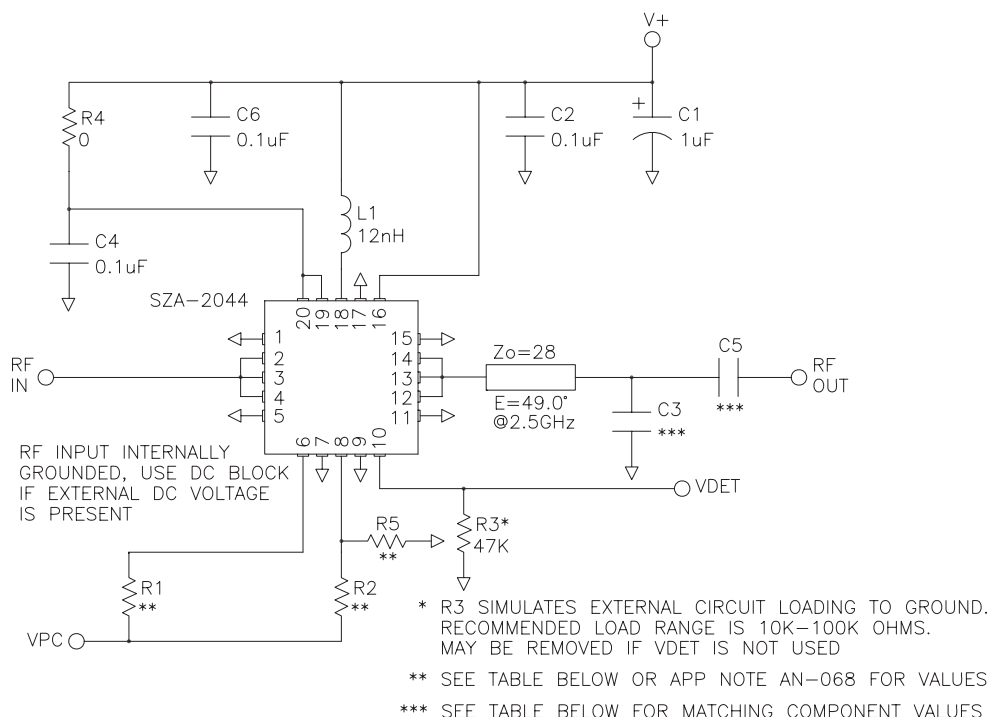


SZA-2044 - 85/15 Sn/Pb plating
SZA-2044Z - Matte Sn plating

Part Symbolization

The part will be symbolized with an “SZA-2044” for Sn/Pb plating or “SZA-2044Z” for RoHS green compliant product. Marking designator will be on the top surface of the package.

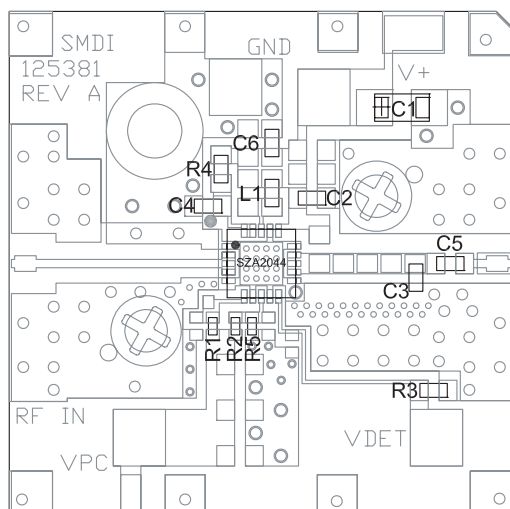
2.0GHz to 2.7GHz Evaluation Board Schematic For $V^+ = V_{CC} = 5.0$



For $V_{CC}=3.3V$ application circuit, contact Applications Engineering.

Important Note: Pins 1, 2, 4, 5, 7, 9, 11, 13, 15, 17, 19 are unwired (N/C) inside the package. Refer to page 2 for detailed pin descriptions. Some of these pins are wired to adjacent pins or grounded as shown in the application circuit. This is to maintain consistency with the evaluation board layout shown below. It is recommended to use this layout and wiring to achieve the specified performance.

Evaluation Board Layout and Bill of Materials



DESG	DESCRIPTION
Q1	SZA-2044
R1	See Table 2, 0402 1%
R2	See Table 2, 0402 1%
R3	47K OHM, 0603 or 0402
R4	0 OHM, 0603 or 0402
R5	See Table 2, 0402 1%
C1	1uF 16V TANTALUM CAP
C2,4,6	0.1uF CAP, 0603 or 0402
C3	See Table 1, 0603
C5	See Table 1, 0603
L1	33nH IND, 0603 (TOKO LL1608-FH33NJ OR EQUIV)

Freq. Range	C3	C5
2.0 - 2.2 GHz	1.0pF	15pF
2.3 - 2.7 GHz	0.5pF	15pF

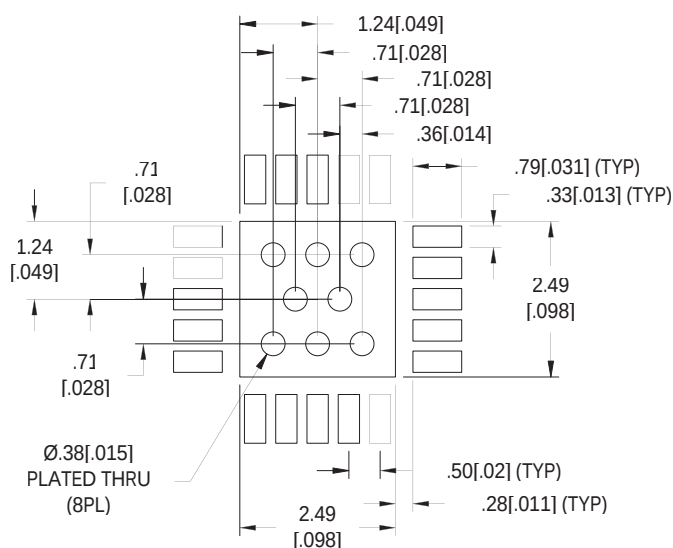
Table 1: Output matching capacitor values ($V_{CC}=5V$, $I_q=302mA$)

VPC(V)	R1	R2	R5
2.9	34.8	27.4	OUT
3.0	121	105	OUT
3.1	205	182	OUT
3.2	287	261	OUT
3.3	374	332	OUT
5.0	1.82K	1.10K	4.75K

Table 2: Resistor values for $V_{PC}=2.9V$ to $5V$ ($V_{CC}=5V$, $I_q=302mA$)

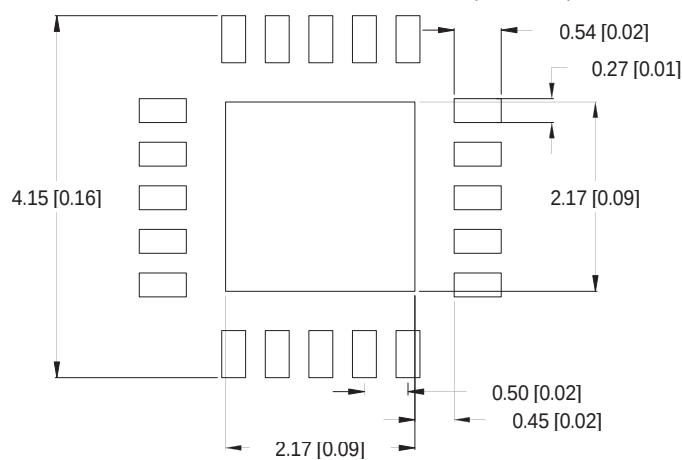
Recommended Land Pattern

Dimensions in millimeters (inches)



Recommended PCB Soldermask (SMB0C) for Land Pattern

Dimensions in millimeters (inches)



Ordering Information

Part Number	Description	Reel Size	Devices/Reel
SZA-2044(Z)	Lead Free RoHS Compliant	13"	3000
SZA-2044(Z)-EVB2	2.0GHz to 2.7GHz Evaluation Board	N/A	N/A